



60V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	R _{DS} (ON) Max	I _D Tc = +25°C
60V	$10m\Omega$ @ V _{GS} = $10V$	89.5A
60 V	$12m\Omega$ @ $V_{GS} = 4.5V$	81.7A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

PowerDI5060-8

PowerDI5060-8/SWP (Type UX)

- High-frequency switching
- · Synchronous rectifications
- DC-DC converters

Features

- Rated to +175°C—Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production— Ensures More Reliable and Robust End Application
- Low Rds(ON)—Minimizes Power Losses
- Low Q_G—Minimizes Switching Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

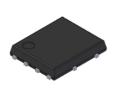
 An automotive-compliant part is available under separate datasheet (<u>DMTH6009LPSQ</u>)

Mechanical Data

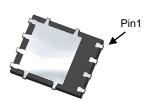
- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish—Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (23)
- Weight: 0.097 grams (Approximate)

Site 1:

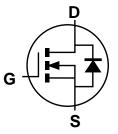
Site 2:



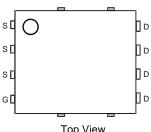
Top View



Bottom View



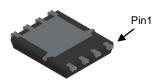
Internal Schematic



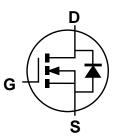




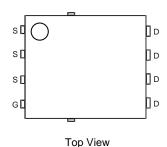




Bottom View



Internal Schematic



Pin Configuration

Ordering Information (Note 4)

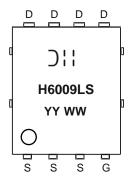
Part Number	Package	Packing		
Part Number	rackaye	Qty.	Carrier	
DMTH6009LPS-13	PowerDI5060-8	2500	Tape & Reel	
DMTH6009LPS-13	PowerDI5060-8/SWP (Type UX)	2500	Tape & Reel	

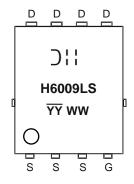
Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information





) | | = Manufacturer's Code Marking H6009LS = Product Type Marking Code YYWW = Date Code Marking YY or \overline{YY} = Year (ex: 23 = 2023) WW = Week (01 to 53)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		VDSS	60	V
Gate-Source Voltage		Vgss	±16	V
Continuous Drain Current (Note 5)	$T_A = +25^{\circ}C$ $T_A = +100^{\circ}C$	I _D	11.76 8.3	А
Continuous Drain Current (Note 6)	$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$	ID	89.5 63.3	А
Maximum Continuous Body Diode Forward Current (Note 6)		Is	89	Α
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I _{DM}	350	Α
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)		Ism	350	Α
Avalanche Current, L = 0.1mH		las	20.3	Α
Avalanche Energy, L = 0.1mH		E _{AS}	20.6	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	2.8	W
Thermal Resistance, Junction to Ambient (Note 5)		RθJA	53	°C/W
Total Power Dissipation (Note 6)	Tc = +25°C	PD	136	W
Thermal Resistance, Junction to Case (Note 6)		R ₀ JC	1.1	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Notes: 5. Device mounted on FR-4 substrate PCB, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.

6. Thermal resistance from junction to soldering point (on the exposed drain pad).



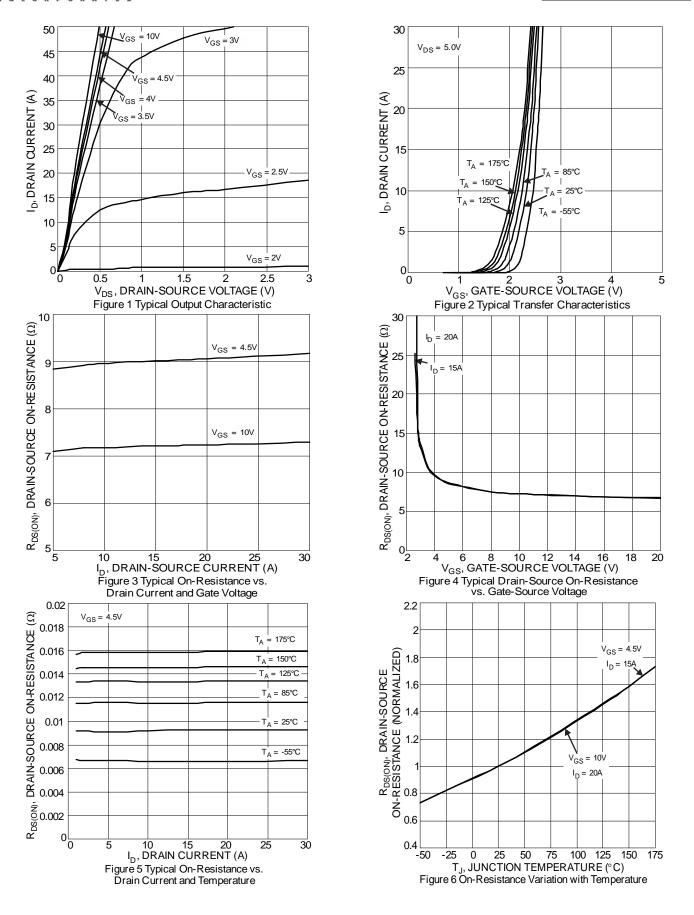
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BVDSS	60	_	_	V	$V_{GS} = 0V$, $I_D = 1mA$
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 48V$, $V_{GS} = 0V$
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 16V$, $V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	Vgs(TH)	0.7	_	2	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$
Static Drain-Source On-Resistance	Daggan	_	7.2	10	mΩ	$V_{GS} = 10V, I_{D} = 20A$
Static Drain-Source On-Nesistance	RDS(ON)	_	8.9	12	11152	$V_{GS} = 4.5V, I_D = 15A$
Diode Forward Voltage	VsD	_	0.9	_	V	$V_{GS} = 0V$, $I_{S} = 20A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	_	1925	_		V 20V V 0V
Output Capacitance	Coss	_	438	_	pF	$V_{DS} = 30V$, $V_{GS} = 0V$, $f = 1MHz$
Reverse Transfer Capacitance	Crss	_	41	_		
Gate Resistance	Rg	_	1.7	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$
Total Gate Charge (V _{GS} = 10V)	Qg	_	33.5	_		
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	15.6		nC	Vps = 30V. lp = 13.5A
Gate-Source Charge	Qgs	_	4.7	_	IIC	VDS = 30 V, ID = 13.5A
Gate-Drain Charge	Q_{gd}	_	5.3	_		!
Turn-On Delay Time	t _D (ON)	_	4.5	_		
Turn-On Rise Time	t _R	_	8.6	_	200	$V_{DD} = 30V, V_{GS} = 10V,$
Turn-Off Delay Time	tD(OFF)	_	35.9	_	ns	$R_G = 6\Omega$, $I_D = 13.5A$
Turn-Off Fall Time	tF	_	15.7	_		
Body Diode Reverse Recovery Time	t _{RR}	_	18.2	_	ns	I_ 42.50 di/dt 4000/
Body Diode Reverse Recovery Charge	Qrr	_	33.1	_	nC	I _F = 13.5A, di/dt = 400A/μs

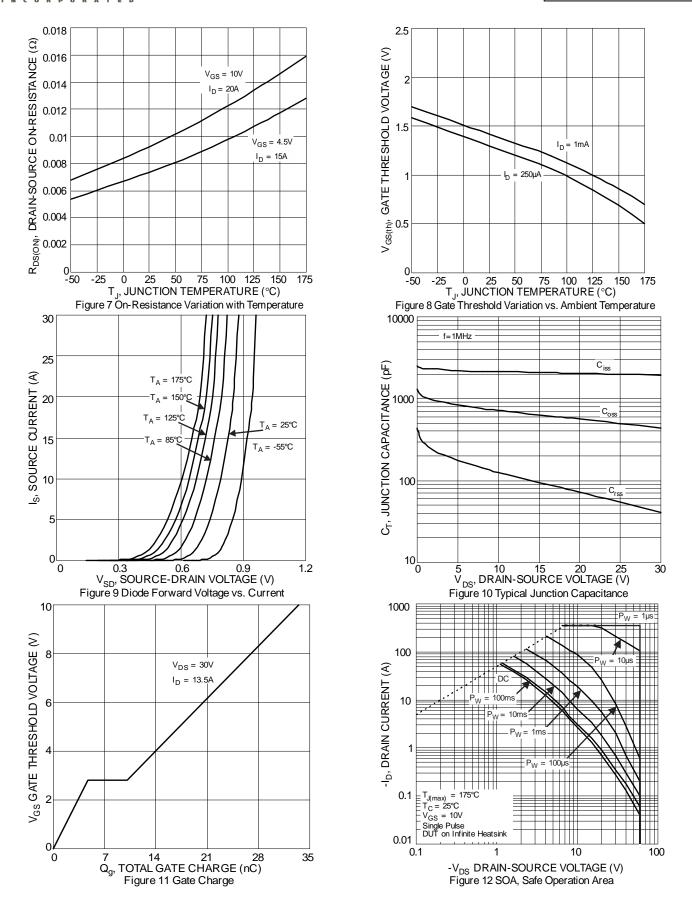
Notes:

^{7.} Short duration pulse test used to minimize self-heating effect. 8. Guaranteed by design. Not subject to product testing.

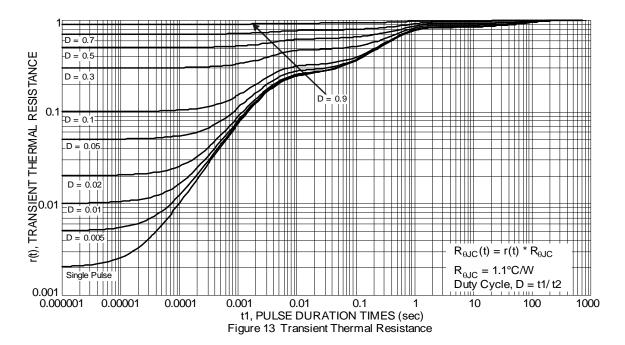












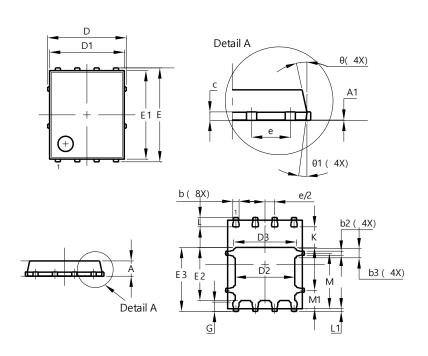


Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

Site 1:

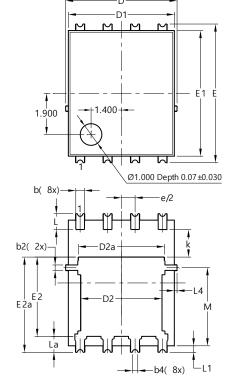
PowerDI5060-8

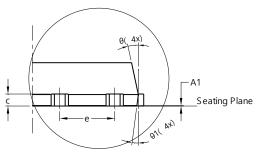


PowerDI5060-8				
Dim	Min	Max	Тур	
Α	0.90	1.10	1.00	
A1	0.00	0.05	_	
b	0.33	0.51	0.41	
b2	0.200	0.350	0.273	
b3	0.40	0.80	0.60	
С	0.230	0.330	0.277	
D	ļ	5.15 BSC	;	
D1	4.70	5.10	4.90	
D2	3.70	4.10	3.90	
D3	3.90	4.30	4.10	
Е	(6.15 BSC	;	
E1	5.60	6.00	5.80	
E2	3.28	3.68	3.48	
E3	3.99	4.39	4.19	
е		1.27 BSC		
G	0.51	0.71	0.61	
K	0.51	ı	-	
L	0.51	0.71	0.61	
L1	0.100	0.200	0.175	
M	3.235	4.035	3.635	
M1	1.00	1.40	1.21	
Θ	10°	12°	11°	
Θ1	6°	8°	7°	
All Dimensions in mm				

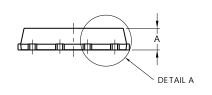
Site 2:

PowerDI5060-8/SWP (Type UX)





DETAIL A



PowerDI5060-8/SWP (Type UX)			
Dim	Min	Max	Тур
Α	0.90	1.10	1.00
A1	0	0.05	
b	0.30	0.50	0.41
b2	0.20	0.35	0.25
b4).25REF	
С	0.230	0.330	0.277
D	5	.15 BS0)
D1	4.70	5.10	4.90
D2	3.56	3.96	3.76
D2a	3.78	4.18	3.98
E	6	.40 BS0)
E1	5.60	6.00	5.80
E2	3.46	3.86	3.66
E2a	4.195	4.595	4.395
е	1	.27BSC)
k	1.05		-
L	0.635	0.835	0.735
La	0.635	0.835	0.735
L1	0.200	0.400	0.300
L1a	0.050REF		
L4	0.025	0.225	0.125
М	3.205	4.005	3.605
θ	10°	12°	11°
θ1	6°	8°	7°
All Dimensions in mm			

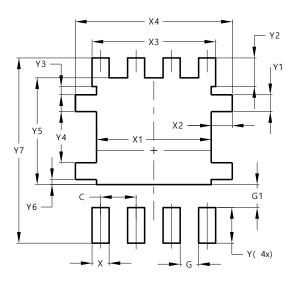


Suggested Pad Layout

 $\label{prop:lease} Please see \ http://www.diodes.com/package-outlines.html for the latest version.$

Site 1:

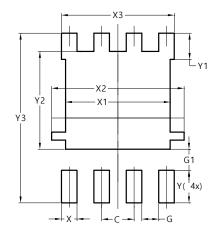
PowerDI5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
Х3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610

Site 2:

PowerDI5060-8/SWP (Type UX)



Dimensions	Value
Diffictions	(in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	5.190
Х3	4.420
Υ	1.270
Y1	1.020
Y2	3.810
Y3	6.610



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